

MS34N02

N-Channel 30-V (D-S) MOSFET

Description

The MS34N02 is the highest performance trench N-ch MOSFETs with extreme high cell density, which provide excellent $R_{DS(ON)}$ and gate charge for most of the small power switching and load switch applications.

The device meets the RoHS and Green Product requirement with full function reliability approved.

Features

- Advanced high cell density Trench technology
- Low $R_{DS(ON)}$
- Green Device Available

Typical Applications

- Battery Protection
- Load Switch
- Hand-held Instrument

Package type : SOT-23

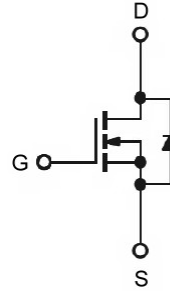
Packing & Order Information

3,000/Reel

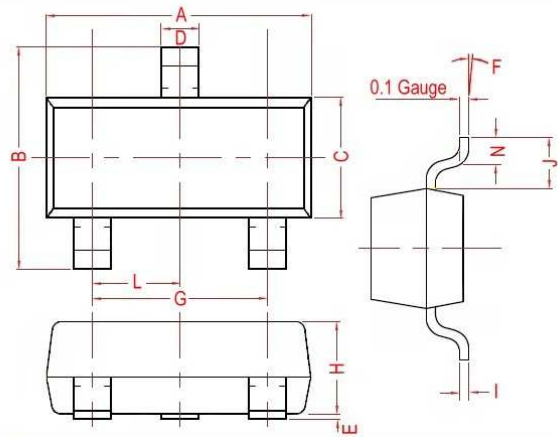


RoHS Compliant

Graphic Symbol

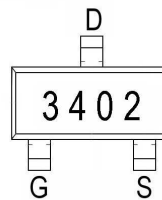


Package Dimension



REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	2.70	3.10	G	1.90 Ref.	
B	2.30	3.00	H	0.90	1.30
C	1.20	1.75	I	0.05	0.21
D	0.30	0.50	J	0.58 Ref.	
E	0.01	0.15	L	0.95 Typ.	
F	0°	10°	N	0.20 Min.	

Marking



MS34N02

N-Channel 30-V (D-S) MOSFET

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings (unless otherwise specified)

Symbol	Parameter	Value	Units
V_{DS}	Drain-Source Voltage	30	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Continuous Drain Current ³ ($T_A=25^\circ\text{C}$)	4.6	A
	Continuous Drain Current ³ ($T_A=70^\circ\text{C}$)	3.7	A
I_{DM}	Pulsed Drain Current ^{1,2} ($T_A=25^\circ\text{C}$)	16	A
P_D	Power Dissipation ($T_A=25^\circ\text{C}$)	1.38	W
T_J/T_{STG}	Operating Junction and Storage Temperature	-55 to +150	$^\circ\text{C}$

Thermal Resistance Ratings

Symbol	Parameter	Maximum	Units
$R_{\theta JA}$	Maximum Junction-to-Ambient ³	90	$^\circ\text{C/W}$

Electrical Characteristics ($T_J=25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}$, $I_D=250\mu\text{A}$	1.0	-	2.5	V
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS}=0\text{V}$, $I_D=250\mu\text{A}$	30	-	-	V
g_{fs}	Forward Transconductance	$V_{DS}=5\text{V}$, $I_D=4.6\text{A}$	-	5	-	S
I_{GSS}	Gate-Source Leakage Current	$V_{DS}=0\text{V}$, $V_{GS}=\pm 20\text{V}$	-	-	± 100	nA
I_{DSS}	Drain-Source Leakage Current	$V_{DS}=24\text{V}$, $V_{GS}=0\text{V}$, $T_J=25^\circ\text{C}$	-	-	1	μA
		$V_{DS}=24\text{V}$, $V_{GS}=0\text{V}$, $T_J=55^\circ\text{C}$	-	-	5	μA
$R_{DS(on)}$	Static Drain-Source On-Resistance ²	$V_{GS}=10\text{V}$, $I_D=4.6\text{A}$	-	-	28	m Ω
		$V_{GS}=4.5\text{V}$, $I_D=4.0\text{A}$	-	-	40	m Ω
V_{SD}	Diode Forward Voltage ²	$I_S=1.25\text{A}$, $V_{GS}=0\text{V}$, $T_J=25^\circ\text{C}$	-	-	1.2	V
I_S	Continuous Source Current (Diode)	$V_G=V_D=0\text{V}$, Force Current	-	-	4.6	A
I_{SM}	Pulsed Source Current (Diode)		-	-	9.2	

Notes

1. Pulsed width limited by maximum junction temperature.
2. The data tested by pulsed, pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$.
3. Surface mounted on 1 in² copper pad of FR4 board; 270 $^\circ\text{C/W}$ when mounted on min. copper pad.

MS34N02

N-Channel 30-V (D-S) MOSFET

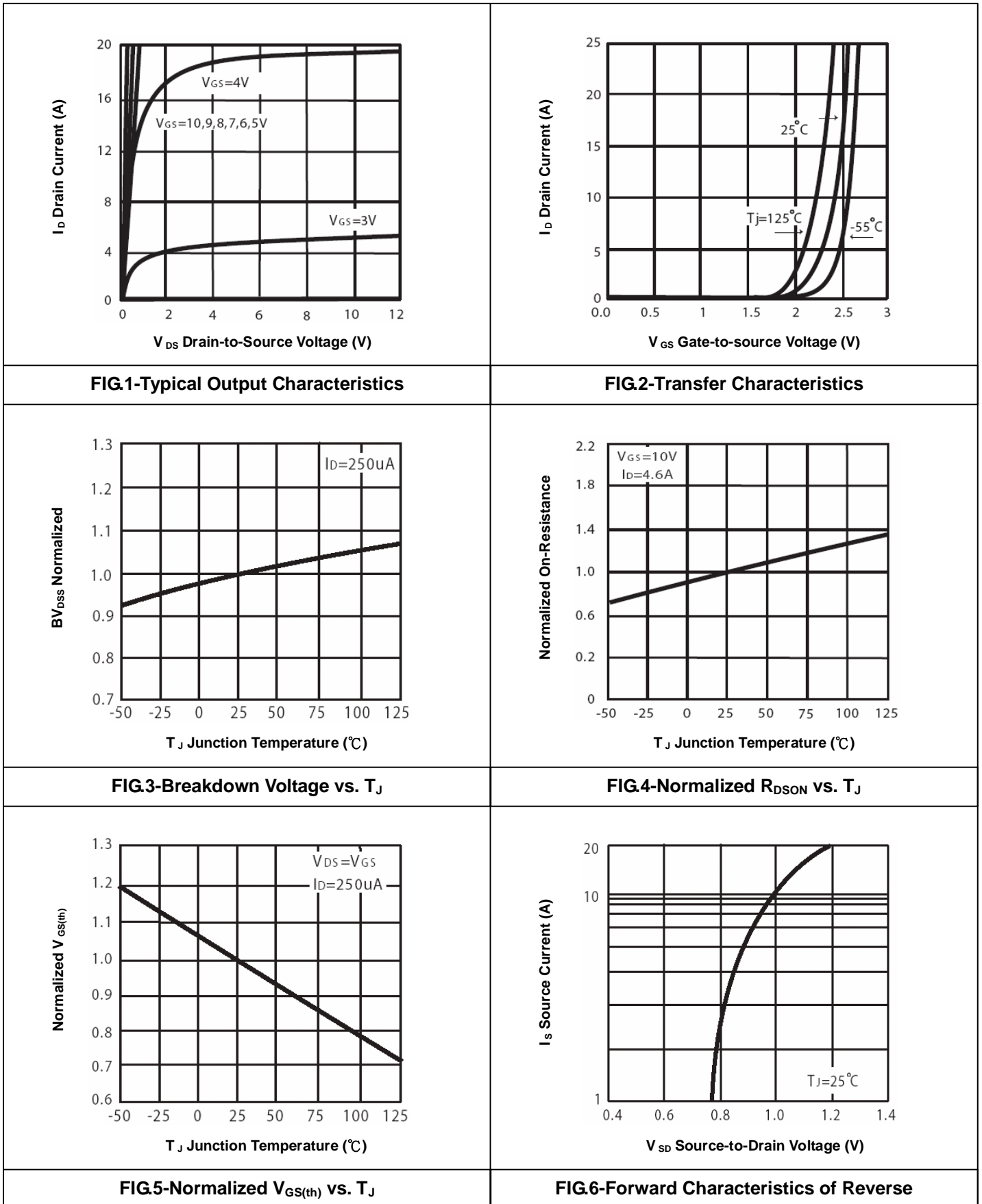
Dynamic and switching Characteristics

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
Q_g	Total Gate Charge ²	$V_{DS}=15V$	--	15.8	--	nC
Q_{gs}	Gate-Source Charge	$I_D=4.6A$	--	2	--	
Q_{gd}	Gate-Drain Charge	$V_{GS}=10V$	--	3	--	
$t_{d(on)}$	Turn-On Delay Time	$V_{DS}=15V$	--	4.8	--	ns
t_r	Rise Time	$I_D=1A$	--	3.9	--	
$t_{d(off)}$	Turn-Off Delay Time	$V_{GS}=10V$	--	27.7	--	
t_f	Fall Time	$R_G=6.0\Omega, R_L=15\Omega$	--	5.5	--	
C_{ISS}	Input Capacitance	$V_{DS}=15V$	--	782	--	pF
C_{OSS}	Output Capacitance	$V_{GS}=0V$	--	135	--	
C_{RSS}	Reverse Transfer Capacitance	$f=1.0MHz$	--	93	--	

MS34N02

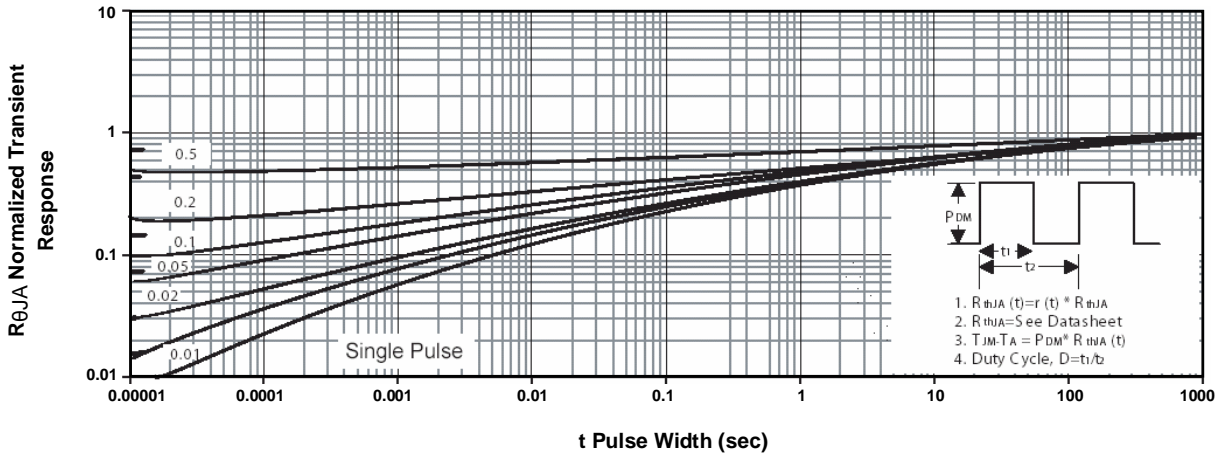
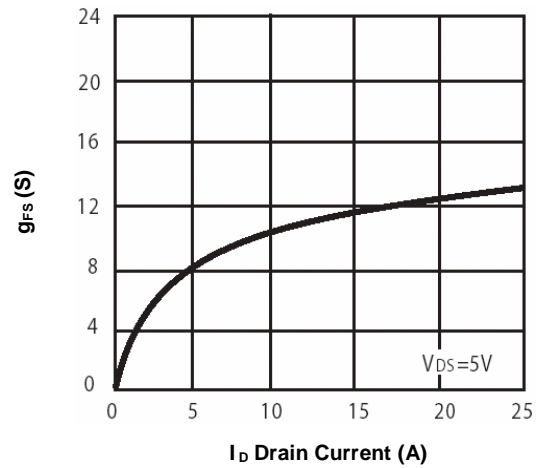
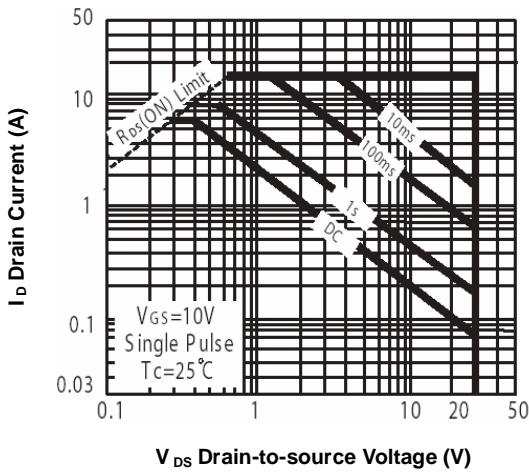
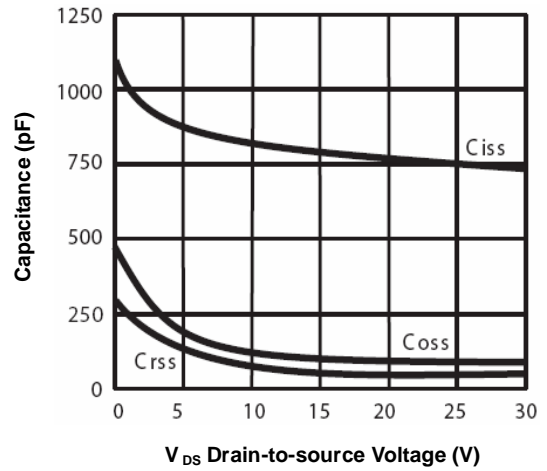
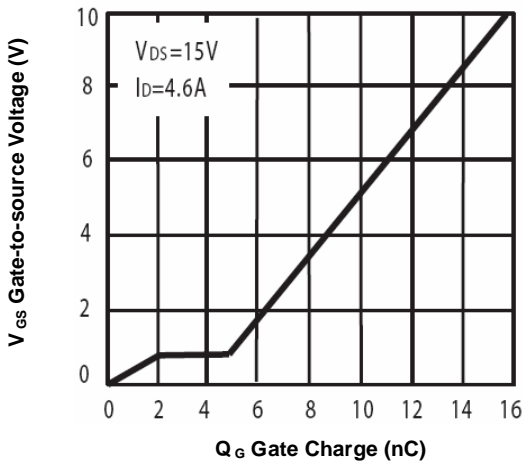
N-Channel 30-V (D-S) MOSFET

- Typical Electrical Characteristics



MS34N02

N-Channel 30-V (D-S) MOSFET



MS34N02

N-Channel 30-V (D-S) MOSFET

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Bruckewell Technology Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Bruckewell"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product. Bruckewell makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Bruckewell disclaims

- (i) Any and all liability arising out of the application or use of any product.
- (ii) Any and all liability, including without limitation special, consequential or incidental damages.
- (iii) Any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Bruckewell's knowledge of typical requirements that are often placed on Bruckewell products in generic applications.

Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time.

Product specifications do not expand or otherwise modify Bruckewell's terms and conditions of purchase, including but not limited to the warranty expressed therein.